**BF908; BF908R** 

**Dual-gate MOS-FETs** 

Rev. 03 — 14 November 2007

**Product data sheet** 

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NXP Semiconductors



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#### FEATURES

- High forward transfer admittance
- Short channel transistor with high forward transfer admittance to input capacitance ratio
- Low noise gain controlled amplifier up to 1 GHz.

### APPLICATIONS

• VHF and UHF applications with 12 V supply voltage, such as television tuners and professional communications equipment.

#### DESCRIPTION

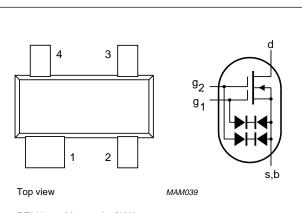
Depletion type field-effect transistor in a plastic microminiature SOT143 or SOT143R package. The transistors are protected against excessive input voltage surges by integrated back-to-back diodes between gates and source.

CAUTION
The device is supplied in an antistatic package. The
gate-source input must be protected against static
discharge during transport or handling.

#### PINNING

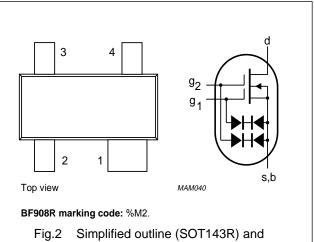
PIN	SYMBOL	DESCRIPTION
1	s, b	source
2	d	drain
3	<b>g</b> 2	gate 2
4	g <sub>1</sub>	gate 1

### QUICK REFERENCE DATA



BF908 marking code: %M1.

Fig.1 Simplified outline (SOT143) and symbol; BF908.



symbol; BF908R.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>DS</sub>	drain-source voltage		_	-	12	V
I <sub>D</sub>	drain current		-	-	40	mA
P <sub>tot</sub>	total power dissipation		-	-	200	mW
Tj	operating junction temperature		-	-	150	°C
y <sub>fs</sub>	forward transfer admittance		36	43	50	mS
C <sub>ig1-s</sub>	input capacitance at gate 1		2.4	3.1	4	pF
C <sub>rs</sub>	reverse transfer capacitance	f = 1 MHz	20	30	45	pF
F	noise figure	f = 800 MHz	-	1.5	2.5	dB

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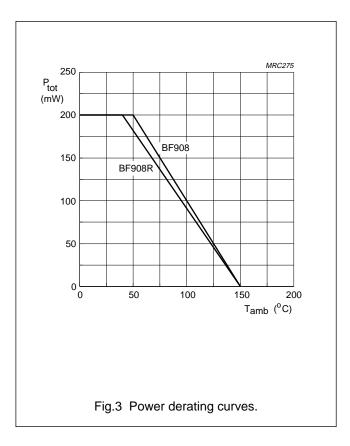
#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>DS</sub>	drain-source voltage		-	12	V
ID	drain current		-	40	mA
±l <sub>G1</sub>	gate 1 current		-	10	mA
±I <sub>G2</sub>	gate 2 current		-	10	mA
P <sub>tot</sub>	total power dissipation	see Fig.3; note 1			
	BF908	up to T <sub>amb</sub> = 50 °C	-	200	mW
	BF908R	up to T <sub>amb</sub> = 40 °C	-	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	operating junction temperature		-	150	°C

#### Note

1. Device mounted on a printed-circuit board.



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### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1		
	BF908		500	K/W
	BF908R		550	K/W

#### Note

1. Device mounted on a printed-circuit board.

### STATIC CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ ; unless otherwise specified.

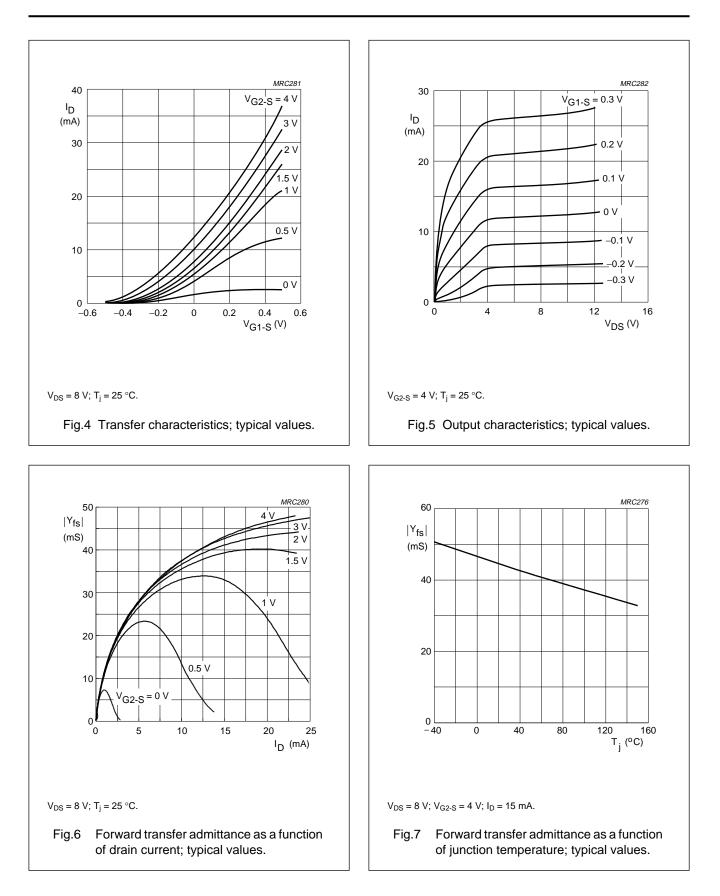
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
±V <sub>(BR)G1-SS</sub>	gate 1-source breakdown voltage	$V_{G2-S} = V_{DS} = 0; I_{G1-S} = 10 \text{ mA}$	8	_	20	V
±V <sub>(BR)G2-SS</sub>	gate 2-source breakdown voltage	$V_{G1-S} = V_{DS} = 0; I_{G2-S} = 10 \text{ mA}$	8	_	20	V
-V <sub>(P)G1-S</sub>	gate 1-source cut-off voltage	$V_{G2-S} = 4 \text{ V}; V_{DS} = 8 \text{ V}; I_D = 20 \mu\text{A}$	-	-	2	V
-V <sub>(P)G2-S</sub>	gate 2-source cut-off voltage	$V_{G1-S} = 4 V; V_{DS} = 8 V; I_D = 20 \mu A$	-	-	1.5	V
I <sub>DSS</sub>	drain-source current	$V_{G2-S} = 4 V; V_{DS} = 8 V; V_{G1-S} = 0$	3	15	27	mA
±I <sub>G1-SS</sub>	gate 1 cut-off current	$V_{G2-S} = V_{DS} = 0; V_{G1-S} = 5 V$	-	_	50	nA
±I <sub>G2-SS</sub>	gate 2 cut-off current	$V_{G1-S} = V_{DS} = 0; V_{G2-S} = 5 V$	-	-	50	nA

### DYNAMIC CHARACTERISTICS

Common source;  $T_{amb} = 25 \text{ °C}$ ;  $V_{DS} = 8 \text{ V}$ ;  $V_{G2-S} = 4 \text{ V}$ ;  $I_D = 15 \text{ mA}$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
y <sub>fs</sub>	forward transfer admittance	pulsed; T <sub>j</sub> = 25 °C; f = 1 MHz	36	43	50	mS
C <sub>ig1-s</sub>	input capacitance at gate 1	f = 1 MHz	2.4	3.1	4	pF
C <sub>ig2-s</sub>	input capacitance at gate 2	f = 1 MHz	1.2	1.8	2.5	pF
C <sub>os</sub>	output capacitance	f = 1 MHz	1.2	1.7	2.2	pF
C <sub>rs</sub>	reverse transfer capacitance	f = 1 MHz	20	30	45	fF
F	noise figure	$f = 200 \text{ MHz}; G_S = 2 \text{ mS}; B_S = B_{Sopt}$	-	0.6	1.2	dB
		$f = 800 \text{ MHz}; G_S = G_{Sopt}; B_S = B_{Sopt}$	-	1.5	2.5	dB

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f	s <sub>11</sub>		s <sub>21</sub>		s <sub>12</sub>		\$ <sub>22</sub>	
(MHz)	MAGNITUDE (ratio)	ANGLE (deg)	MAGNITUDE (ratio)	ANGLE (deg)	MAGNITUDE (ratio)	ANGLE (deg)	MAGNITUDE (ratio)	ANGLE (deg)
V <sub>DS</sub> = 8	3 V; V <sub>G2-S</sub> = 4 V; I	l <sub>D</sub> = 10 mA	; T <sub>amb</sub> = 25 °C.					
50	0.998	-5.1	3.537	173.5	0.001	98.2	0.996	-2.4
100	0.994	-10.4	3.502	167.7	0.001	88.8	0.994	-4.9
200	0.979	-20.8	3.450	154.9	0.003	74.6	0.987	-9.5
300	0.962	-30.3	3.318	143.7	0.004	69.5	0.983	-13.9
400	0.939	-40.1	3.234	131.9	0.005	65.6	0.980	-18.5
500	0.914	-49.1	3.093	120.7	0.006	64.4	0.974	-22.8
600	0.892	-57.1	2.912	111.1	0.005	63.1	0.969	-27.0
700	0.865	-64.4	2.774	101.0	0.005	65.2	0.966	-31.2
800	0.837	-71.6	2.616	91.4	0.004	70.8	0.965	-35.4
900	0.811	-78.1	2.479	81.9	0.004	87.4	0.965	-39.4
1000	0.785	-84.5	3.329	72.5	0.003	108.0	0.966	-43.7
V <sub>DS</sub> = 8	3 V; V <sub>G2-S</sub> = 4 V; I	l <sub>D</sub> = 15 mA	.; T <sub>amb</sub> = 25 °C.					
50	0.998	-5.3	3.983	173.4	0.001	95.5	0.994	-2.4
100	0.994	-10.9	3.943	167.5	0.001	93.6	0.991	-5.0
200	0.976	-21.6	3.878	154.7	0.003	74.3	0.984	-9.7
300	0.957	-31.7	3.722	143.3	0.004	70.0	0.979	-14.2
400	0.934	-41.7	3.614	131.6	0.005	63.5	0.975	-18.8
500	0.907	-51.1	3.446	120.4	0.006	62.2	0.969	-23.2
600	0.885	-59.1	3.240	110.9	0.005	59.6	0.964	-27.4
700	0.851	-66.8	3.072	100.9	0.005	64.8	0.961	-31.6
800	0.826	-73.9	2.891	91.3	0.004	67.8	0.959	-35.9
900	0.797	-80.7	2.733	81.9	0.004	85.0	0.958	-40.0
1000	0.773	-87.0	2.569	72.8	0.004	102.9	0.958	-44.2

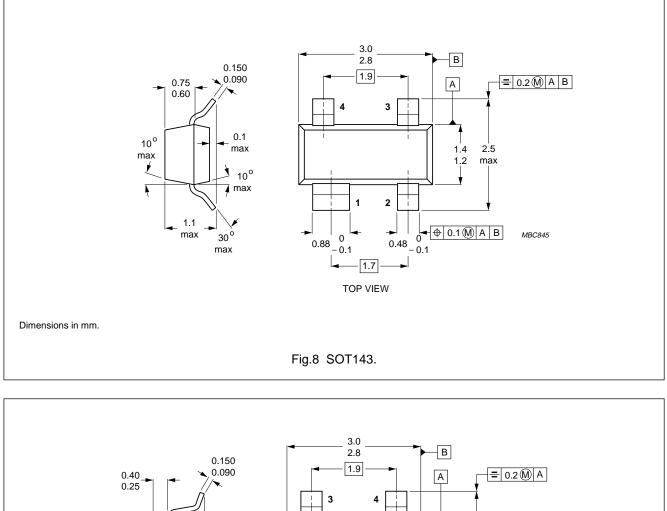
### **Table 1**Scattering parameters

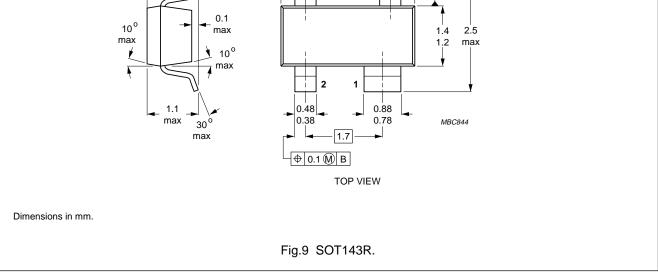
### Table 2 Noise data

f	F <sub>min</sub>	$\Gamma_{opt}$		-	
(MHz)	(dB)	(ratio)	(deg)	r <sub>n</sub>	
$V_{DS} = 8 V; V_{G2-S} = 4 V;$	<sub>D</sub> = 10 mA; T <sub>amb</sub> = 25 °C.				
800	1.50	0.720	56.7	0.580	
$V_{DS}$ = 8 V; $V_{G2-S}$ = 4 V; $I_D$ = 15 mA; $T_{amb}$ = 25 °C.					
800	1.50	0.700	59.2	0.520	

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#### PACKAGE OUTLINES





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### Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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# **Revision history**

### Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BF908-R_N_3	20071114	Product data sheet	-	BF908-R_2	
Modifications:	<ul> <li>Fig. 1 and 2 on page 2; Figure note changed</li> </ul>				
BF908-R_2	19960730	Product specification	-	BF908R_1	
BF908R_1	-	-	-	-	

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